

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







MA27P11

Silicon epitaxial planar type

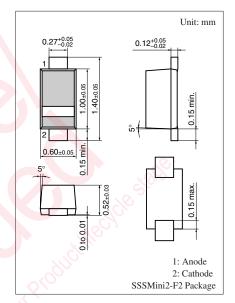
For high frequency switch

■ Features

- Low terminal capacitance
- Low forward dynamic resistance
- SSS-Mini type 2-pin package

■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit	
Reverse voltage	V_R	60	V	
Forward current	I_{F}	50	mA	
Junction temperature	T _j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



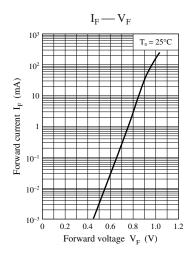
Marking Symbol: F

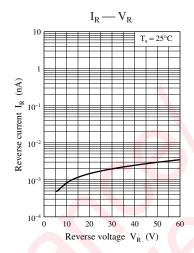
■ Electrical Characteristics T_a = 25°C ± 3°C

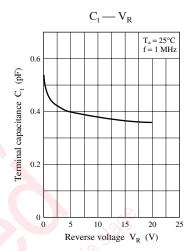
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V_{F1}	$I_F = 1 \text{ mA}$	1.90	0.76	0.85	V
	V_{F2}	I _F = 10 mA		0.85	1.00	V
Reverse current	I_R	$V_R = 60 \text{ V}$		1.0	100	nA
Terminal capacitance	C _t	$V_R = 0 V, f = 1 MHz$		0.55	0.80	pF
Forward dynamic resistance	r _{fl}	$I_F = 1 \text{ mA, } f = 100 \text{ MHz}$		1.6	3.0	Ω
	r_{f2}	$I_F = 10 \text{ mA}, f = 100 \text{ MHz}$		0.9	1.5	Ω

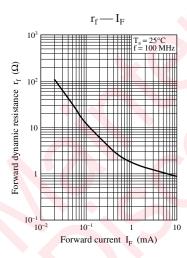
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

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